

Schott[®] Borofloat[®] 33 Borosilicate Wafers

Material Description

The performance requirements for wafers used for anodic bonding or as a carrier in wafer thinning processes are mainly determined by their ability to perfectly match those of the silicon wafer to which they shall be bonded. Well-adapted thermal expansion behavior is as important as excellent flatness and process robustness. BOROFLOAT® wafers provide these along with exceptionally high UV transmission.

Wafer Options

Coresix produces Schott® BOROFLOAT® 33 wafers to all SEMI Standards including dimensional, flat and notch specifications. In addition, we offer custom specifications designed to your unique needs including, alignment marks, holes, pockets, edge profile, thickness, flatness, surface quality, cleanliness or other details critical to your application.

Wafer Specifications

Standard	Best
50.8, 76.2, 100, 150, 200, 300, 450	Custom Diameters
+/- 200µm	+/- 50 μm
.3, .4, .5, .7, 1.1 mm	Custom .45mm - 5.0mm
+/- 10%	+/- 5 µm
<30µm	<1µm
80/50	5/2
<7Å	<3Å
<400µm	<30µm
λ per Inch TIR	λ /10 per Inch TIR
	50.8, 76.2, 100, 150, 200, 300, 450 +/- 200µm .3, .4, .5, .7, 1.1 mm +/- 10% <30µm 80/50 <7Å

Electrical Properties

Dielectric Strength (25°C, 50Hz)	16 kV/mm
Dielectric Constant (25°C,1MHz)	4.6
Loss Tangent (25°C, 1MHz)	37 x 10 ⁻⁴
Electric Volume Resistivity (250°C)	8.0
Electric Volume Resistivity (350°C)	6.5

Thermal Properties

Thermal Coefficient of Expansion (20-300°C)	3.25 x 10 ⁻⁶ K ⁻¹
Specific Thermal Capacity (20-100°C)	0.83 KJ x (kg x K) ⁻¹
Specific Thermal Conductivity (90°C)	(1.2W x (m x K) ⁻¹
Annealing Point	560°C / 1040°F
Softening Point	815°C / 1508°F
Thermal Conductivity	1.2 W/mk @90°C
Maximum Operating Temperature Considering RTG (Resistance to Thermal Gradients) and RTS (Resistance to Thermal Shock)	
Short Term	500°C / 932°F
Long Term	450°C / 842°F

Mechanical Properties

Density (25°C / 77°F)	2.23 g/cm ³
Modulus of Elasticity	63 kN/mm ²
Young's Modulus (25°C / 77°F)	64 kN/mm ²
Knoop Hardness HK	0.1/20:480
Poisson's Ratio	0.2
Bending Strength	25 MPa

Optical Properties

Refractive Index	1.471
Index of Refraction	
@435.8nm	1.48
@589.3nm	1.47
@656.3nm	1.46
Dispersion	71.4 x 10 ⁻⁴
Abbe Constant	65.41

